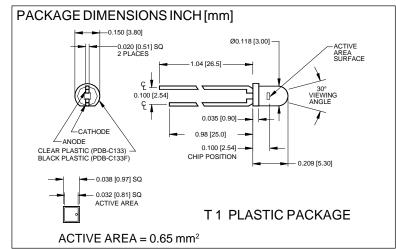
PHOTONIC Silicon Photodiode, Blue Enhanced Photoconductive **DETECTORS INC.** Type PDB-C133, with daylight filter Type PDB-C133F





FEATURES

- Photoconductive
- High speed
- Low cost

DESCRIPTION: The **PDB-C133** detector is a 0.65 mm² planar pin photodiode packaged

in a T 1, water clear plastic housing. Designed for high speed, low capacitance,

photoconductive applications. The **PDB-C133F** includes a daylight filter.

APPLICATIONS

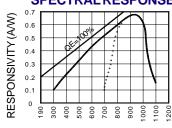
- Smoke detectors
- Light pen detectors
- TV & VCR remotes

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS
V_{BR}	Reverse Voltage		100	V
T _{STG}	Storage Temperature	-40	+100	∘C
T _o	Operating Temperature Range	-40	+80	∘C
T _s	Soldering Temperature*		+260	∘C
I _L	Light Current		0.5	mA

^{*1/16} inch from case for 3 secs max

SPECTRAL RESPONSE



WAVELENGTH (nm)

ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

(17.1-20 0 4.1101.100 0 1.100.100.00)								
SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS		
I _{sc}	Short Circuit Current	H = 100 fc, 2850 K	12	15		μ A		
I _D	Dark Current	H = 0, V _R = 10 V		2	10	nA		
R _{SH}	Shunt Resistance	$H = 0, V_R = 10 \text{ mV}$.5	5		GΩ		
TCR _{SH}	RSH Temp. Coefficient	$H = 0, V_R = 10 \text{ mV}$		-8		%/°C		
C _J	Junction Capacitance	H = 0, V _R = 10 V*		2	5	pF		
λrange	Spectral Application Range	(without daylight filter)**	400		1100	nm		
λр	Spectral Response - Peak			950		nm		
V _{BR}	Breakdown Voltage	I = 10 μA	50	100		V		
NEP	Noise Equivalent Power	V _R = 10 V @ Peak		1.5x10 ⁻¹³		W/ √Hz		
tr	Response Time	$RL = 1 K\Omega V_p = 10 V$		5		nS		